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74ALVC16835 Low Voltage 18-Bit Universal Bus Driver with 3.6V Tolerant Inputs and Outputs

General Description

The ALVC16835 low voltage 18-bit universal bus driver combines D-type latches and D-type flip-flops to allow data flow in transparent, latched and clocked modes.

Data flow is controlled by output-enable (\overline{OE}) , latch-enable (LE), and clock (CLK) inputs. The device operates in Transparent Mode when LE is held HIGH. The device operates in clocked mode when LE is LOW and CLK is toggled. Data transfers from the Inputs (In) to Ouputs (On) on a Positive Edge Transition of the Clock. When \overline{OE} is LOW, the output data is enabled. When \overline{OE} is HIGH the output port is in a high impedance state.

The 74ALVC16835 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74ALVC16835 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- Compatible with PC100 DIMM module specifications
- 1.65V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD} (CLK to O_n)
 - 4.5 ns max for 3.0V to 3.6V V_{CC} 5.5 ns max for 2.3V to 2.7V V_{CC} 9.2 ns max for 1.65V to 1.95V V_{CC}
- Power-off high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Latchup conforms to JEDEC JED78
- ESD performance:

Human body model > 2000V Machine model > 200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} (OE to GND) through a pulldown resistor; the minimum value of the resistor is determined by the current sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74ALVC16835MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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DS500645

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Connection Diagram

		,	1
NC -	1	56	-GND
NC -	2	55	- NC
O ₁ —	3	54	-1 ₁
GND_	4	53	-GND
02 —	5	52	-I ₂
O ₃ —	6	51	– I ₃
V _{cc} —	7	50	$-v_{cc}$
04 —	8	49	— 14
O ₅ —	9	48	— I ₅
06-	10	47	–۱ ₆
GND-	11	46	GND
07-	12	45	– 1 ₇
08 —	13	44	— I ₈
09 🗕	14	43	— l9
010 -	15	42	-I ₁₀
011	16	4 1	-111
012 -	17	40	-1 ₁₂
GND -	18	39	- GND
013 -	19	38	-1 ₁₃
O ₁₄ —	20	37	-1 ₁₄
O ₁₅ —	21	36	-۱ ₁₅
V _{cc} —	22	35	−v _{cc}
O ₁₆ —	23	34	-1 ₁₆
017-	24	33	-1 ₁₇
GND-	25	32	-GND
0 ₁₈ —	26	3 1	−1 ₁₈
ÖË —	27	30	-CLK
LE -	28	29	-GND

Pin Descriptions

Pin Names	Description
ŌE	Output Enable Input (Active LOW)
LE	Latch Enable Input
CLK	Clock Input
I ₁ - I ₁₈	Data Inputs
O ₁ - O ₁₈	3-STATE Outputs
NC	No Connect

Truth Table

	Inp	Outputs		
OE	LE	CLK	In	O _n
Н	Х	Х	Х	Z
L	Н	Χ	L	L
L	Н	Χ	Н	Н
L	L	\uparrow	L	L
L	L	\uparrow	Н	Н
L	L	Н	X	O ₀ (Note 2)
L	L	L	X	O ₀ (Note 3)

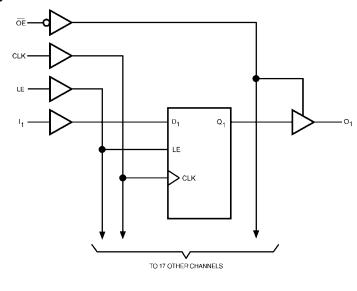
- H = Logic HIGH
 L = Logic LOW
 X = Don't Care, but not floating
- Z = High Impedance

 ↑ = LOW-to-HIGH Clock Transition

Note 2: Output level before the indicated steady-state input conditions were established provided that CLK was HIGH before LE went LOW.

Note 3: Output level before the indicated steady-state input conditions

Logic Diagram



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Absolute Maximum Ratings(Note 4)

 $\begin{tabular}{lll} Supply Voltage (V_{CC}) & -0.5V to +4.6V \\ DC Input Voltage (V_I) & -0.5V to 4.6V \\ \end{tabular}$

Output Voltage (V_O) (Note 5) -0.5V to V_{CC} +0.5V

DC Input Diode Current (I_{IK})

 $V_I < 0V$ –50 mA

DC Output Diode Current (I_{OK})

 $V_{O} < 0V$ –50 mA

DC Output Source/Sink Current

 (I_{OH}/I_{OL}) $\pm 50 \text{ mA}$

DC V_{CC} or GND Current per

Supply Pin (I_{CC} or GND) ±100 mA

Storage Temperature Range (T_{STG}) -65°C to +150°C

Recommended Operating Conditions (Note 6)

Power Supply

Operating 1.65V to 3.6V Input Voltage (V_1) 0V to V_{CC}

Output Voltage (V_O) OV to V_{CC}

Free Air Operating Temperature (T_A) $-40^{\circ}C$ to $+85^{\circ}C$

Minimum Input Edge Rate (Δt/ΔV)

 $V_{IN} = 0.8V \text{ to } 2.0V, V_{CC} = 3.0V$ 10 ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: $\rm I_{O}$ Absolute Maximum Rating must be observed, limited to 4.6V.

Note 6: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC}	Min	Max	Units
Syllibol	Parameter	Conditions	(V)	IVIIII	IVIAA	Onits
V _{IH}	HIGH Level Input Voltage		1.65 - 1.95	0.65 x V _{CC}		
			2.3 - 2.7	1.7		V
			2.7 - 3.6	2.0		
V _{IL}	LOW Level Input Voltage		1.65 - 1.95		0.35 x V _{CC}	
			2.3 - 2.7		0.7	V
			2.7 - 3.6		0.8	
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu\text{A}$	1.65 - 3.6	V _{CC} - 0.2		
		I _{OH} = -4 mA	1.65	1.2		
		I _{OH} = -6 mA	2.3	2.0		
		I _{OH} = -12 mA	2.3	1.7		V
			2.7	2.2		
			3.0	2.4		
		I _{OH} = -24 mA	3.0	2		
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	1.65 - 3.6		0.2	
		I _{OL} = 4 mA	1.65		0.45	
		I _{OL} = 6 mA	2.3		0.4	V
		I _{OL} = 12 mA	2.3		0.7	v
			2.7		0.4	
		I _{OL} = 24 mA	3.0		0.55	
I _I	Input Leakage Current	$0 \le V_1 \le 3.6V$	3.6		±5.0	μΑ
I _{OZ}	3-STATE Output Leakage	0 ≤ V _O ≤ 3.6V	3.6		±10	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6		40	μΑ
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	3 - 3.6		750	μΑ

AC Electrical Characteristics

		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, R_L = 500\Omega$										
Symbol	Parameter		C _L = 50 pF					C _L = 30 pF				
Symbol		Farameter		$V_{CC}=3.$	3V ± 0.3V	v _{cc}	= 2.7V	V _{CC} = 2.5	5V ± 0.2V	V _{CC} = 1.8	8V ± 0.15V	Units
			Min	Max	Min	Max	Min	Max	Min	Max		
f _{CLOCK}	Clock Freque	ency			150		150		150		100	MHz
t _W	Pulse Width	LE High		3.3		3.3		3.3		4.0		ns
		CLK High or Low		3.3		3.3		3.3		4.0		115
t _S	Setup Time	Data Before CLK	↑	1.7		2.1		2.2		2.5		
		Data Before LE ↓ CLK High	CLK High	1.5		1.6		1.9				ns
			CLK Low	1.0		1.1		1.3				
t _H	Hold Time	Data After CLK ↑		0.7		0.6		0.6		1.0		
		Data After LE ↓	CLK High or Low	1.4		1.7		1.4				ns
f _{MAX}	Maximum CI	ock Frequency	•	150		150		150		100		MHz
t _{PHL} , t _{PLH}	Propagation	Propagation Delay I to O		1	3.6		4.2	1.0	4.2	1.5	8.4	
	LE to		LE to O	1.3	4.2		4.9	1.3	5.0	1.5	9.8	ns
		CLK to O		1.4	4.5		5.2	1.4	5.5	2	9.2	
t _{PZL} , t _{PZH}	Output Enable Time		1.1	4.6		5.6	1.4	5.5	1.5	9.8	ns	
t _{PLZ} , t _{PHZ}	Output Disab	ole Time		1.3	3.9		4.3	1.0	4.5	1.5	7.6	ns

AC Electrical Characteristics Over Load (Note 7)

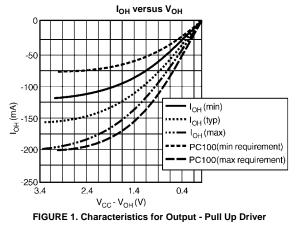
Symbol	Parameter	$T_A = -0^{\circ}C$	to +85°C	$T_A = -0^{\circ}C$ to $+65^{\circ}C$		Units	
Symbol	Falantee	C _L = 0 pF		C _L = 50 pF		Onics	
		Min	Max	Min	Max		
t _{PHL} , t _{PLH}	Propagation Delay Bus to Bus	0.9	2.0	1.0	4.0	ns	
t _{PHL} , t _{PLH}	Propagation Delay Clock to Bus	1.5	2.9	1.7	4.5	ns	

Note 7: This parameter is guaranteed by characterization but not tested.

Capacitance

Symbol	Parameter		Conditions	T _A =	Units	
Symbol			Conditions	v _{cc}	Typical	Ullits
C _{IN}	Input Capacitance	Control	$V_I = 0V$ or V_{CC}	3.3	3	pF
		Data	$V_I = 0V$ or V_{CC}	3.3	6	þi
C _{OUT}	Output Capacitance		$V_I = 0V$ or V_{CC}	3.3	7	pF
C _{PD}	Power Dissipation Capacitance	Outputs Enabled	f = 10 MHz, C _L = 0 pF	3.3	31	
				2.5	26	pF
		Outputs Disabled	f = 10 MHz, C _L = 0 pF	3.3	14	þi
				2.5	12	

\mathbf{I}_{OUT} - \mathbf{V}_{OUT} Characteristics





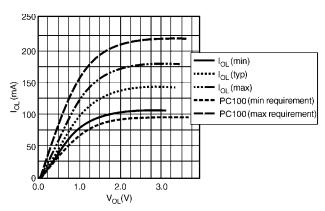


FIGURE 2. Characteristics for Output - Pull Down Driver

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AC Loading and Waveforms

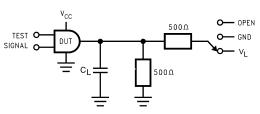


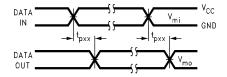
TABLE 1.

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t_{PZL}, t_{PLZ}	V _L
t _{PZH} , t _{PHZ}	GND

FIGURE 3. AC Test Circuit

TABLE 2. Variable Matrix (Input Characteristics: $f=1 MHz; \, t_r=t_f=2 ns; \, Z_0=50 \Omega)$

Symbol	V _{CC}							
Symbol	$3.3V \pm 0.3V$	2.7V	$2.5V \pm 0.2V$	1.8 ± 0.15V				
V _{mi}	1.5V	1.5V	V _{CC} /2	V _{CC} /2				
V _{mo}	1.5V	1.5V	V _{CC} /2	V _{CC} /2				
V _X	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V				
V _Y	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V				
V _L	6V	6V	V _{CC} /*2	V _{CC} /*2				



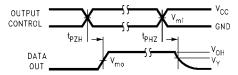


FIGURE 4. Waveform for Inverting and Non-inverting Functions $t_r = t_f \leq 2.0 ns, \, 10\% \ to \ 90\%$

FIGURE 5. 3-STATE Output High Enable and Disable Times for Low Voltage Logic $t_r=t_f\leq 2.0ns,\,10\%\ to\ 90\%$

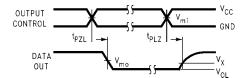
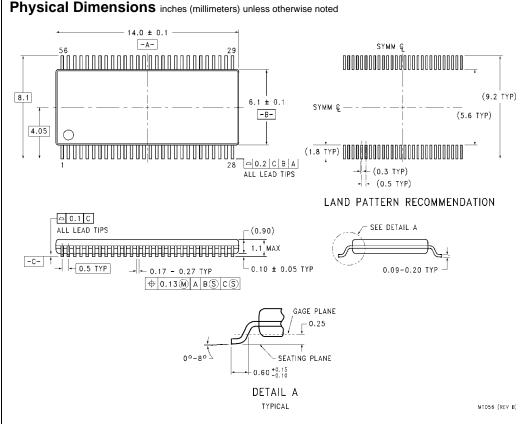


FIGURE 6. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic $t_r=t_f\!\le\!2.0ns,\,10\%$ to 90%



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD56

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